ne<mark>x</mark>peria

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In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

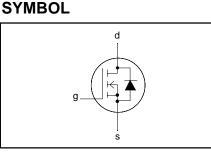
Kind regards,

Team Nexperia

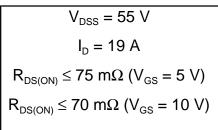
PHP21N06LT, PHB21N06LT PHD21N06LT

FEATURES

- 'Trench' technology
- Low on-state resistance
- Fast switching
- Logic level compatible



QUICK REFERENCE DATA



GENERAL DESCRIPTION

N-channel enhancement mode, logic level, field-effect power transistor in a plastic envelope using 'trench' technology.

Applications:-

- d.c. to d.c. converters
- switched mode power supplies

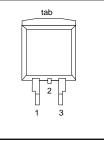
The PHP21N06LT is supplied in the SOT78 (TO220AB) conventional leaded package. The PHB21N06LT is supplied in the SOT404 (D²PAK) surface mounting package. The PHD21N06LT is supplied in the SOT428 (DPAK) surface mounting package.

PINNING

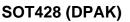
| PIN | DESCRIPTION |
|-----|--------------------|
| 1 | gate |
| 2 | drain ¹ |
| 3 | source |
| tab | drain |

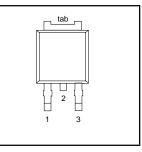


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SOT404 (D²PAK)





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------------------------------|---|---|------|------|------|
| V _{DSS} | Drain-source voltage | T _i = 25 °C to 175°C | - | 55 | V |
| V _{DGR} | Drain-gate voltage | $T_{1} = 25 \text{ °C to } 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$ | - | 55 | V |
| V _{GS} | Gate-source voltage | , | - | ± 15 | V |
| V _{GSM} | Pulsed gate-source voltage | T _i ≤ 150°C | - | ± 20 | V |
| I _D | Continuous drain current | $T'_{mb} = 25 \degree C$ | - | 19 | A |
| - | | $T_{mb} = 100 \text{°C}$ | - | 13 | A |
| I _{DM} | Pulsed drain current | $T_{mb} = 25 \ ^{\circ}C$ | - | 76 | A |
| P _D | Total power dissipation | $T_{mb} = 25 \degree C$ | - | 56 | W |
| T _j , T _{stg} | Operating junction and storage temperature | | - 55 | 175 | °C |

¹ It is not possible to make connection to pin:2 of the SOT404 or SOT428 packages.

PHP21N06LT, PHB21N06LT PHD21N06LT

AVALANCHE ENERGY LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------------|--|---|------|------|------|
| /10 | Non-repetitive avalanche energy | Unclamped inductive load, $I_{AS} = 9.7 \text{ A}$; $t_p = 100 \ \mu\text{s}$; $T_j \text{ prior to avalanche} = 25^{\circ}\text{C}$; $V_{DD} \le 25 \text{ V}$; $R_{GS} = 50 \ \Omega$; $V_{GS} = 5 \text{ V}$; refer to fig:15 | - | 34 | mJ |
| I _{AS} | Peak non-repetitive avalanche current | | - | 19 | A |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | TYP. | MAX. | UNIT |
|----------------------|--|--|----------|------|------------|
| R _{th j-mb} | Thermal resistance junction to mounting base | | - | 2.7 | K/W |
| R _{th j-a} | Thermal resistance junction to ambient | SOT78 package, in free air SOT428 and SOT404 package, pcb mounted, minimum footprint | 60 50 | - | K/W K/W |

ELECTRICAL CHARACTERISTICS

| $T_i = 25^{\circ}C$ unless otherwise specifi |
|--|
|--|

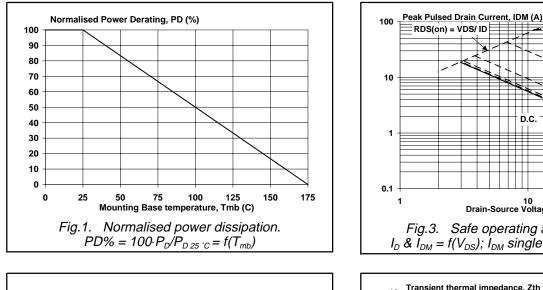
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|-----------------------------|---|------|------|------|---------|
| V _{(BR)DSS} | Drain-source breakdown | $V_{GS} = 0 \text{ V}; \text{ I}_{D} = 0.25 \text{ mA};$ | 55 | - | - | V |
| | voltage | $T_{j} = -55^{\circ}C$ | 50 | - | - | V |
| $V_{GS(TO)}$ | Gate threshold voltage | $V_{DS} = V_{GS}; I_D = 1 \text{ mA}$ | 1.0 | 1.5 | 2.0 | V |
| | | T _j = 175°C T _i = -55°C | 0.5 | - | - | V |
| - | | | - | - | 2.3 | V |
| R _{DS(ON)} | Drain-source on-state | $V_{GS} = 10 \text{ V}; I_{D} = 10 \text{ A}$ | - | 55 | 70 | mΩ |
| | resistance | $V_{GS} = 5 \text{ V}; I_D = 10 \text{ A}$ | - | 60 | 75 | mΩ |
| | | $T_{j} = 175^{\circ}C$ | - | - | 158 | mΩ |
| 9 _{fs} | Forward transconductance | $V_{DS} = 25 \text{ V}; \text{ I}_{D} = 10 \text{ A}$ | 5 | 13 | - | S |
| GSS | Gate source leakage current | $V_{GS} = \pm 5 V; V_{DS} = 0 V$ | - | | 100 | nA |
| DSS | Zero gate voltage drain | $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V};$ | - | 0.05 | 10 | μA |
| | current | T _j = 175°C | - | - | 500 | μΑ |
| Q _{g(tot)} | Total gate charge | $I_{D} = 20 \text{ A}; V_{DD} = 44 \text{ V}; V_{GS} = 5 \text{ V}$ | - | 9.4 | - | nC |
| Q _{gs} | Gate-source charge | | - | 2.2 | - | nC |
| Q_{gd}^{gd} | Gate-drain (Miller) charge | | - | 5.4 | - | nC |
| t _{d on} | Turn-on delay time | $V_{DD} = 30 \text{ V}; \text{ R}_{D} = 1.2 \Omega;$ | - | 7 | 15 | ns |
| t _r | Turn-on rise time | $R_{G} = 10 \Omega; V_{GS} = 5 V$ | - | 88 | 120 | ns |
| | | Resistive load | - | 25 | 40 | ns |
| t _f | Turn-off fall time | | - | 25 | 45 | ns |
| L _d | Internal drain inductance | Measured from tab to centre of die | - | 3.5 | i _ | nH |
| L _d | Internal drain inductance | Measured from drain lead to centre of die | - | 4.5 | - | nH |
| | | (SOT78 package only) | | | | |
| Ls | Internal source inductance | Measured from source lead to source | - | 7.5 | - | nH |
| 3 | | bond pad | | - | | |
| C _{iss} | Input capacitance | V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz | | 466 | 650 | pF |
| C _{oss} | Output capacitance | | - | 95 | 135 | , pF |
| Crss | Feedback capacitance | | | 71 | 85 | pF |

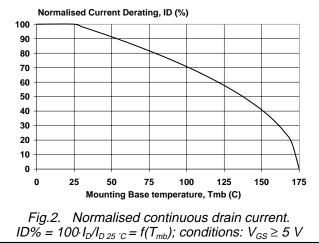
PHP21N06LT, PHB21N06LT PHD21N06LT

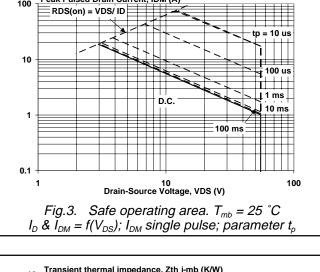
REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

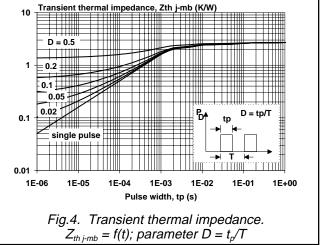
 $T_i = 25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------------|--|--|------|----------|------|----------|
| I _S | Continuous source current (body diode) | | - | - | 19 | А |
| I _{SM} | Pulsed source current (body diode) | | - | - | 76 | А |
| V_{SD} | Diode forward voltage | I _F = 20 A; V _{GS} = 0 V | - | 1.2 | 1.5 | V |
| | Reverse recovery time Reverse recovery charge | $ I_{F} = 20 \text{ A}; -dI_{F}/dt = 100 \text{ A}/\mu\text{s}; \\ V_{GS} = 0 \text{ V}; \text{ V}_{R} = 30 \text{ V} $ | - | 43 94 | - | ns nC |

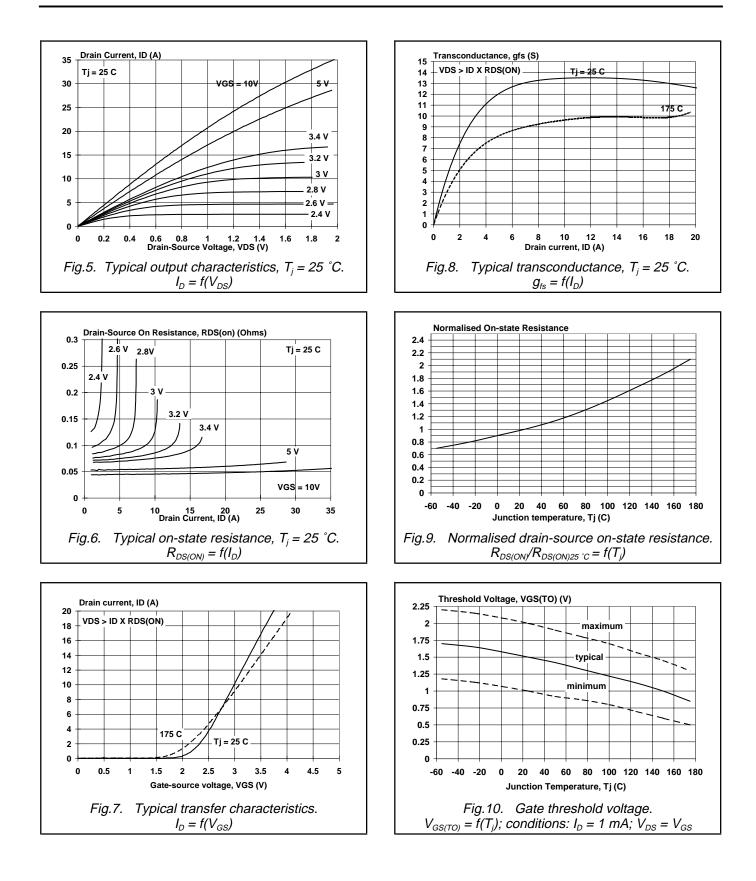




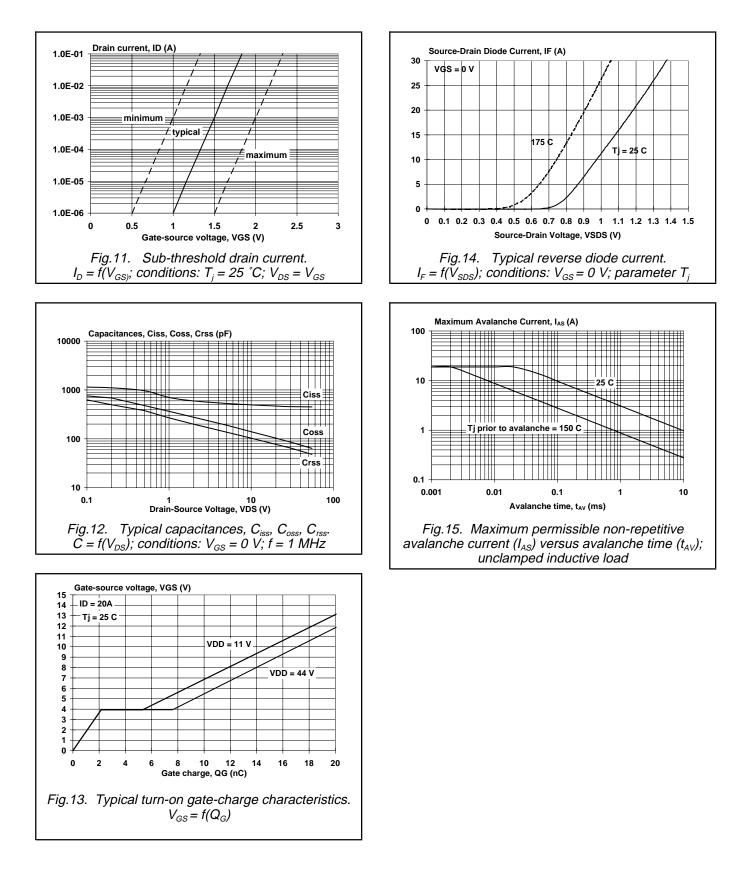




PHP21N06LT, PHB21N06LT PHD21N06LT

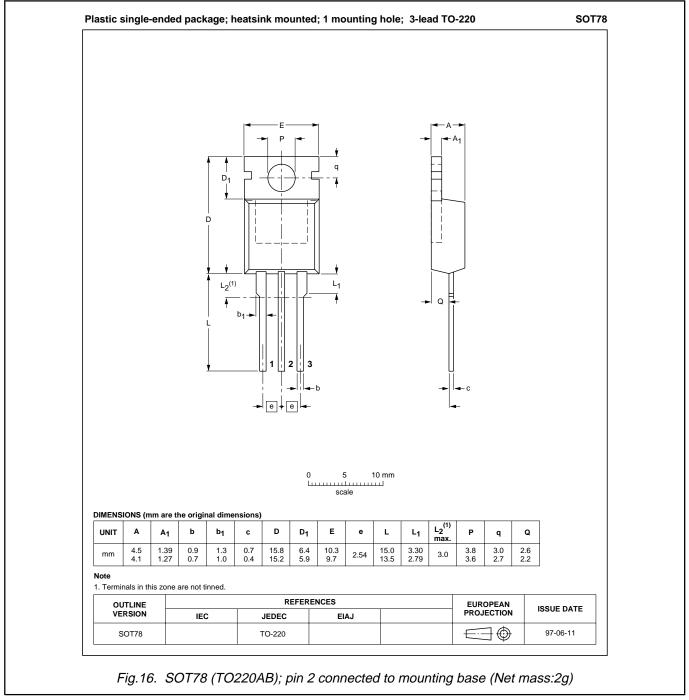


PHP21N06LT, PHB21N06LT PHD21N06LT



PHP21N06LT, PHB21N06LT PHD21N06LT

MECHANICAL DATA

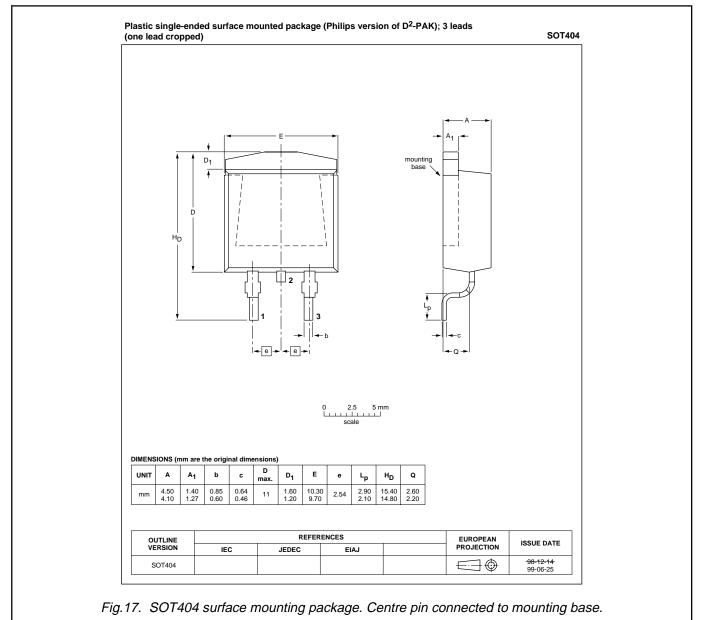


Notes

- 1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
- 2. Refer to mounting instructions for SOT78 (TO220AB) package.
- 3. Epoxy meets UL94 V0 at 1/8".

PHP21N06LT, PHB21N06LT PHD21N06LT

MECHANICAL DATA

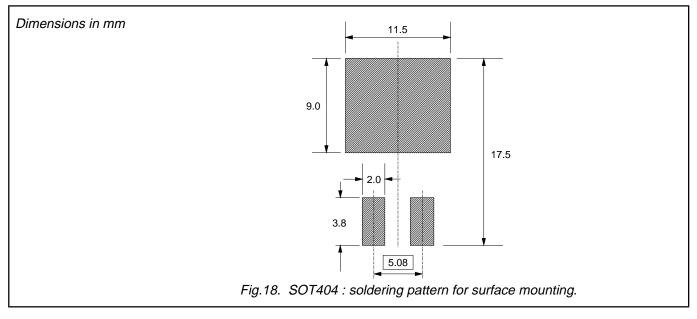


Notes

- 1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
- 2. Refer to SMD Footprint Design and Soldering Guidelines, Data Handbook SC18.
- 3. Epoxy meets UL94 V0 at 1/8".

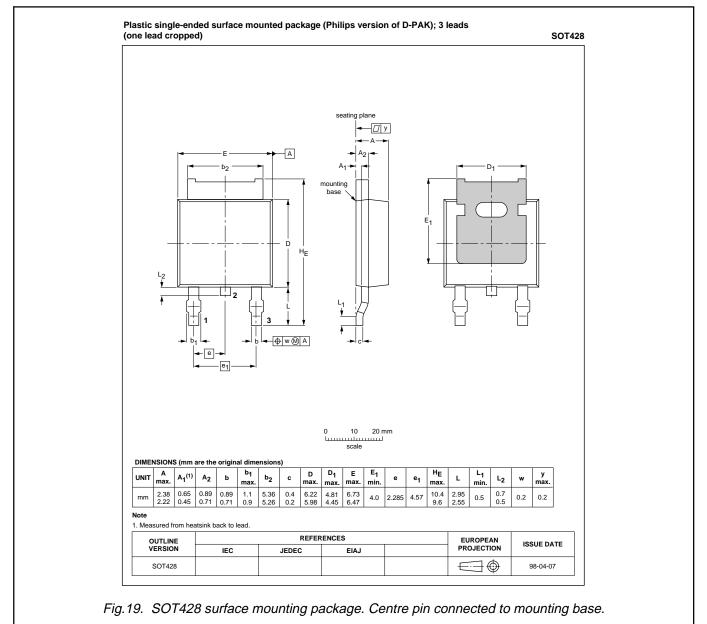
PHP21N06LT, PHB21N06LT PHD21N06LT

MOUNTING INSTRUCTIONS



PHP21N06LT, PHB21N06LT PHD21N06LT

MECHANICAL DATA

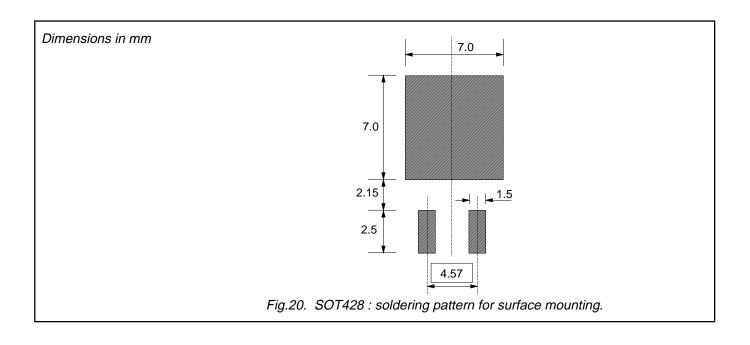


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MOUNTING INSTRUCTIONS

PHP21N06LT, PHB21N06LT PHD21N06LT



PHP21N06LT, PHB21N06LT PHD21N06LT

DEFINITIONS

| Data sheet status | | | | |
|---|--|--|--|--|
| Objective specification | Objective specification This data sheet contains target or goal specifications for product development. | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | |
| Product specification | This data sheet contains final product specifications. | | | |
| Limiting values | | | | |
| or more of the limiting val operation of the device at | Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | |
| Application information | | | | |
| Where application information is given, it is advisory and does not form part of the specification. | | | | |
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